

# NiCd Gas Gauge Module with LEDs for High Discharge Rates

#### **Features**

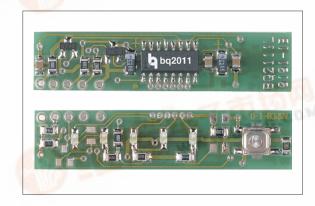
- ➤ Complete bq2011 Gas Gauge solution for NiCd packs in high discharge rate applications
- Five surface-mounted LEDs to display state-of-charge information
- Battery state-of-charge monitoring for 4- to 12-cell series applications
- On-board regulator allows direct connection to the battery
- Battery information available over a single-wire bidirectional serial port
- ➤ Nominal capacity pre-configured
- Compact size for battery pack integration

#### **General Description**

The bq2111L Gas Gauge Module provides a complete and compact solution for capacity monitoring of NiCd battery packs in high discharge rate applications such as power tools. Designed for battery pack integration, the bq2111L incorporates a bq2011 Gas Gauge IC, five surface-mounted LEDs, and the other discrete components necessary to monitor and display accurately the capacity of 4- to 12-series cells. The only external component required is a low-value sense resistor connected between GND and PACK-. Contacts are also provided on the bq2111L for direct connection to the battery stack and the serial communications port (DQ). The battery stack should be connected between BAT+ and GND. Please refer to the bq2011 data sheet for the specifics on the operation of the Gas Gauge.

Unitrode configures the bq2111L based on the information requested in Table 1. The configuration defines the number of series cells and the nominal battery pack capacity. The bq211L module uses the absolute LED display to indicate battery capacity. In this mode, the remaining capacity is represented as a percentage of the programmed capacity.

The bq2111L can operate directly from four series cells within the pack using the LBAT+ supply input. For four series cell applications or applications using the onboard regulator, LBAT+ should be connected to BAT+. Please refer to Figure 1 for module connection illustrations.



A module development kit is also available for the bq2111L. The bq2111LB-KT includes one configured module and the following:

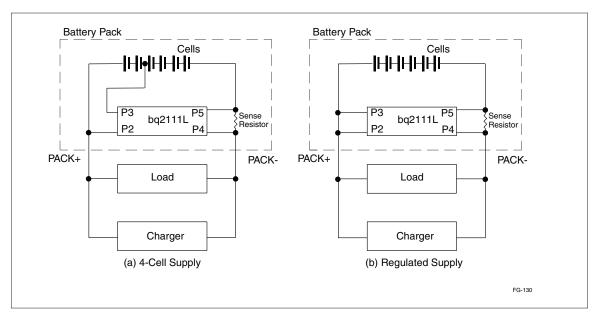
- An interface board that allows connection to the serial port of an AT-compatible computer.
- 2) Menu-driven software with the bq2111L to display charge/discharge activity and to allow user interface to the bq2011 from any standard DOS PC.
- 3) Source code for the TSR.

#### **Pin Descriptions**

- P1 DQ/Serial communication port
- P2 BAT+/Battery positive/Pack positive
- P3 LBAT+/Four--cell power
- P4 PACK-/Pack negative
- P5 GND/Ground



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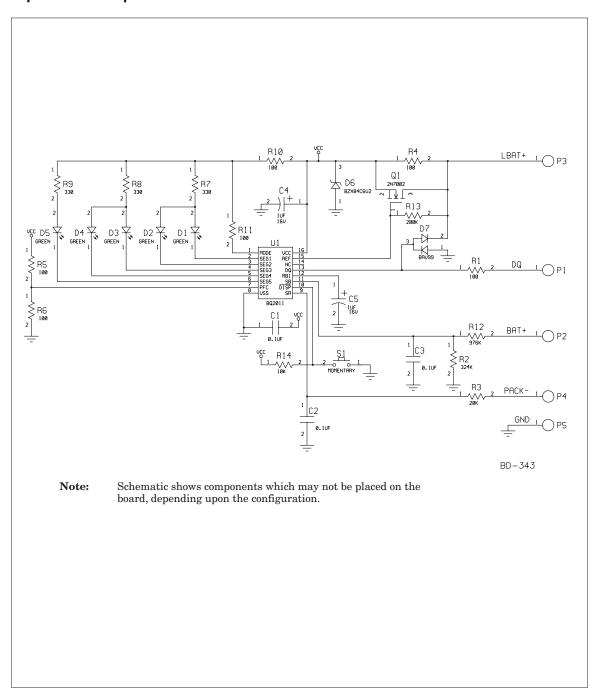
**Figure 1. Module Connection Diagram** 

Table 1. bq2111L Module Configuration

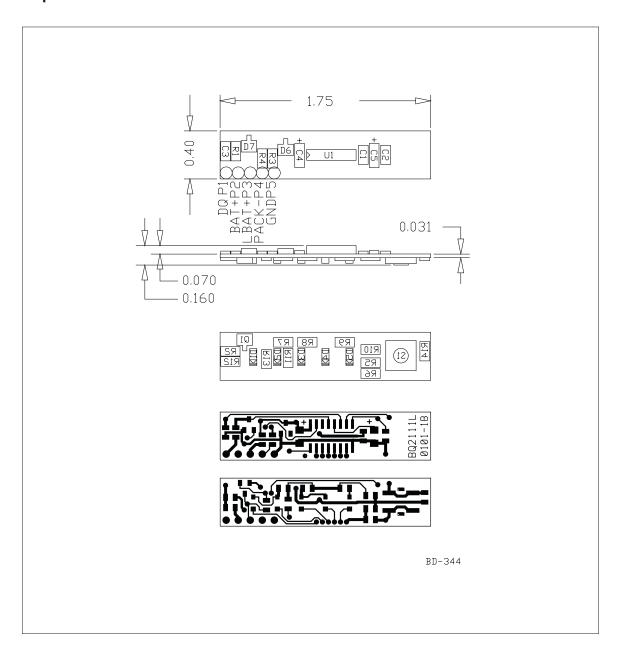
Contact:				
Address:				
Sales Contact:		Phone:		
Number of series battery cells (4-12)				
Sense resistor size in $m\Omega^1$				
Battery pack capacity (mAh)				
Discharge rate(A)	Min	Avg	Max	
Charge rate (A)				
FAE approval:		Date:		

**Note:** 1. Sense resistor is not included with board.

## **bq2111L Example Schematic**



#### bq2111L Board



#### **Absolute Maximum Ratings**

Symbol	Parameter	Minimum	Maximum	Unit	Notes
VCC	Relative to VSS	-0.3	+7.0	V	bq2011
All other pins	Relative to VSS	-0.3	+7.0	V	bq2011
TOPR	Operating temperature	0	+70	°C	Commercial
T <sub>STR</sub>	Storage temperature	-40	+85	°C	

Note:

Permanent device damage may occur if **Absolute Maximum Ratings** are exceeded. Functional operation should be limited to the Recommended DC Operating Conditions detailed in this data sheet. Exposure to conditions beyond the operational limits for extended periods of time may affect device reliability.

#### DC Electrical Characteristics (TA = TOPR)

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Conditions/Notes
NumCell	Number of series cells in battery pack	4	-	12	-	
BAT+	Positive terminal of pack	GND	NumCell * 1.2V	NumCell * 1.8V	V	
$V_{ m SR}$	Voltage across the sense resistor, P4 to P5	-0.3	-	2	V	
$V_{\rm CC}$	Supply voltage (direct cell operation) LBAT+	3.0	4.8	7.2	V	
$I_{CC}$	Supply current at BAT+ terminal (no external loads)	-	120	250	μΑ	
$R_{\mathrm{DQ}}$	Internal pull-down	500k	-	-	$\Omega^1$	
IoL	Open-drain sink current DQ	-	-	5.0	mA <sup>1</sup>	
$V_{OL}$	Open-drain output low, DQ	-	-	0.5	V1	I <sub>OL</sub> < 5mA
VIHDQ	DQ input high	2.5	-	-	$V^1$	
VILDQ	DQ input low	-	-	0.8	$V^1$	
Vos	Voltage offset			150	$\mu V^1$	

Note:

1. Characterized on PCB, IC 100% tested.

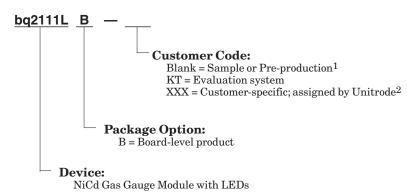
#### DC Voltage Thresholds (TA = TOPR)

Symbol	Parameter	Minimum	Typical	Maximum	Unit	Notes
$V_{\mathrm{EDV}}$	Final empty warning	0.87	0.90	0.93	V	BAT+/NumCell <sup>1</sup>
VMCV	Maximum single-cell voltage	1.95	2.0	2.05	V	BAT+/NumCell <sup>1</sup>
VSR1	Discharge compensation threshold	20	50	75	mV	$V_{SR} + V_{OS}^2$
$V_{\mathrm{SR2}}$	Discharge compensation threshold	70	100	125	mV	$V_{\rm SR}$ + $V_{\rm OS}^2$
$V_{\rm SR3}$	Discharge compensation threshold	120	150	175	mV	$V_{\rm SR}$ + $V_{\rm OS}^2$
$V_{\mathrm{SR4}}$	Discharge compensation threshold	220	253	275	mV	$V_{\rm SR}$ + $V_{\rm OS}^2$
V <sub>SRO</sub>	Sense resistor sense range	-300	-	+2000	mV	$V_{\rm SR}$ + $V_{\rm OS}^2$
VSRQ	Valid charge	-	-	-400	μV	Vsr + Vos <sup>2</sup>
$V_{ m SRD}$	Valid discharge	500	-	-	μV	$V_{SR} + V_{OS}^2$

Notes:

- 1. At SB input of bq2011
- 2. At SR input of bq2011

#### **Ordering Information**



Notes:

- 1. Requires configuration sheet (see Table 1)
- 2. Example production part number: bq2111LB-001

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